# NSN 5962-01-234-8033

Memory Microcircuit - Page 1 of 1



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## Maximum Power Dissipation Rating:

525.0 milliwatts

## **Operating Tempurature Range:**

-0.0/+70.0 degrees celsius

## Storage Tempurature Range:

-65.0/+125.0 degrees celsius

## Features Provided:

Ultraviolet erasable and programmable and static operation

### **Output Logic Form:**

Metal oxide-semiconductor logic

## Input Circuit Pattern:

13 input

**Terminal Surface Treatment:** 

Solder

#### Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 6.0 volts power source

#### **Time Rating Per Chacteristic:**

450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

#### Fiig:

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